PDTC114Y series

NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 47 k Ω

Rev. 7 — 18 November 2011

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			PNP	Package	
	NXP	JEITA	JEDEC	complement	configuration	
PDTC114YE	SOT416	SC-75	'-	PDTA114YE	ultra small	
PDTC114YM	SOT883	SC-101	-	PDTA114YM	leadless ultra small	
PDTC114YT	SOT23	-	TO-236AB	PDTA114YT	small	
PDTC114YU	SOT323	SC-70	-	PDTA114YU	very small	

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	



2. Pinning information

Table 3. **Pinning** Simplified outline **Graphic symbol** Pin Description SOT23; SOT323; SOT416 1 input (base) 3 2 GND (emitter) 3 output (collector) 006aaa144 sym007 **SOT883** 1 input (base) 2 GND (emitter) output (collector) Transparent

3. Ordering information

Table 4. Ordering information

PDTC114YM SC-101 leadless ultra small plastic package; 3 solder lands; SOT body 1.0 × 0.6 × 0.5 mm PDTC114YT - plastic surface-mounted package; 3 leads SOT	Type number	Package	Package					
PDTC114YM SC-101 leadless ultra small plastic package; 3 solder lands; SOT body 1.0 × 0.6 × 0.5 mm PDTC114YT - plastic surface-mounted package; 3 leads SOT		Name	Description					
body $1.0 \times 0.6 \times 0.5 \text{ mm}$ PDTC114YT - plastic surface-mounted package; 3 leads SOT	PDTC114YE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
1	PDTC114YM	SC-101		SOT883				
PDTC114YLL SC-70 plastic surface-mounted package: 3 leads SOT	PDTC114YT	-	plastic surface-mounted package; 3 leads	SOT23				
Placific dell'accommodition package, e leade	PDTC114YU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PDTC114YE	33
PDTC114YM	DU
PDTC114YT	*27
PDTC114YU	*30

[1] * = placeholder for manufacturing site code

5. Limiting values

Table 6. Limiting values

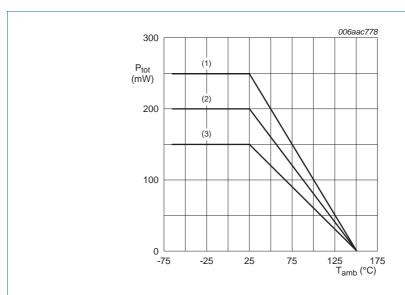
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	50	V
V_{EBO}	emitter-base voltage	open collector	-	6	V
VI	input voltage				
	positive		-	+40	V
	negative		-	-6	V
I _O	output current		-	100	mA
I _{CM}	peak collector current	$single \ pulse; \\ t_p \leq 1 \ ms$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	PDTC114YE (SOT416)		[1][2]	150	mW
	PDTC114YM (SOT883)		[2][3]	250	mW
	PDTC114YT (SOT23)		[1] -	250	mW
	PDTC114YU (SOT323)		[1] -	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70 μm copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

Fig 1. Power derating curves

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTC114YE (SOT416)		[1][2]	-	830	K/W
	PDTC114YM (SOT883)		[2][3]	-	500	K/W
	PDTC114YT (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTC114YU (SOT323)		<u>[1]</u> _	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.

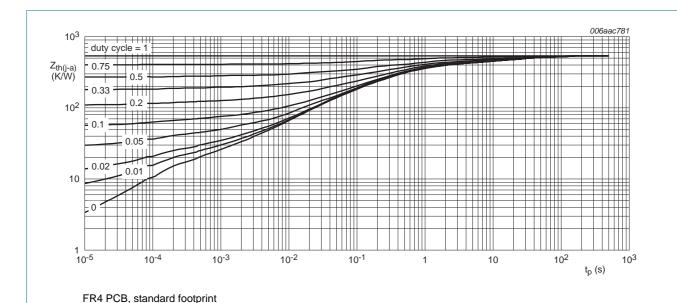
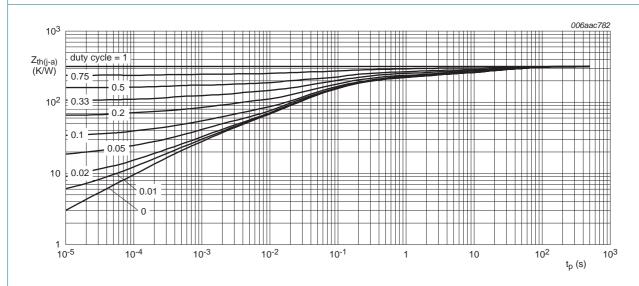
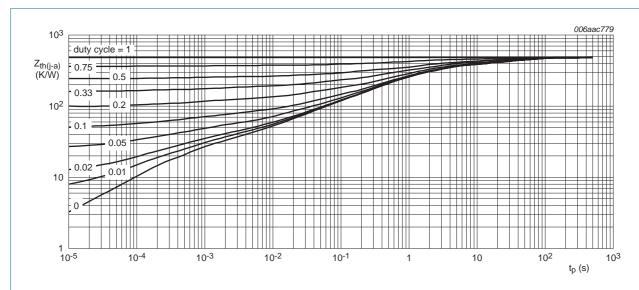


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114YE (SOT416); typical values



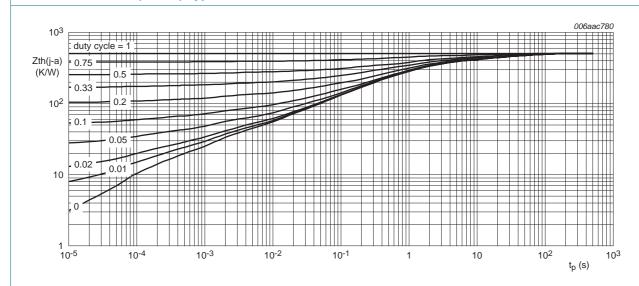
FR4 PCB, 70 µm copper strip line

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114YM (SOT883); typical values



FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114YT (SOT23); typical values



FR4 PCB, standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114YU (SOT323); typical values

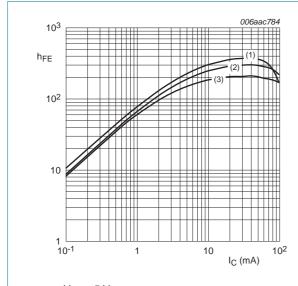
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
I _{CEO}	collector-emitter	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$		-	-	1	μΑ
	cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$		-	-	5	μА
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$		-	-	150	μА
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}$		-	-	100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$		-	0.7	0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 1 \text{ mA}$		1.4	0.8	-	V
R1	bias resistor 1 (input)			7	10	13	kΩ
R2/R1	bias resistor ratio			3.7	4.7	5.7	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz		-	-	2.5	pF
f _T	transition frequency	$V_{CE} = 5 \text{ V; } I_{C} = 10 \text{ mA;}$ f = 100 MHz	[1]	-	230	-	MHz

[1] Characteristics of built-in transistor



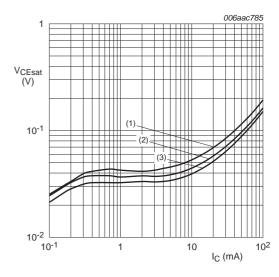


(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 6. DC current gain as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

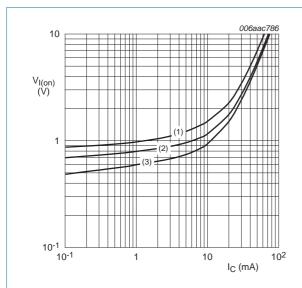
(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values

PDTC114Y_SER

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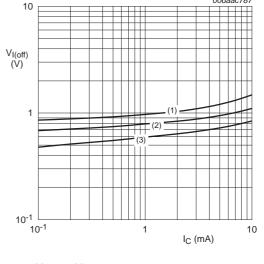
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$$V_{CE} = 0.3 \text{ V}$$

- (1) $T_{amb} = -40 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 100 \, ^{\circ}C$

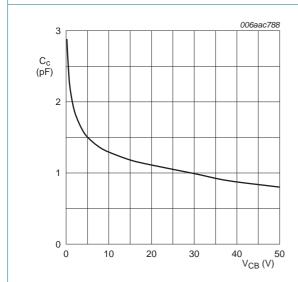
Fig 8. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

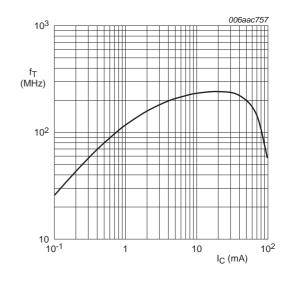
- (1) $T_{amb} = -40 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 100 \, ^{\circ}C$

Fig 9. Off-state input voltage as a function of collector current; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$

Fig 10. Collector capacitance as a function of collector-base voltage; typical values



 V_{CE} = 5 V; T_{amb} = 25 °C

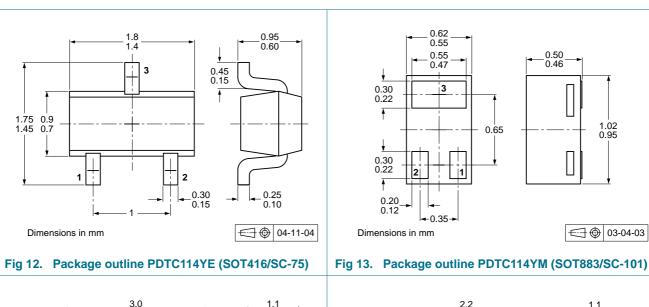
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

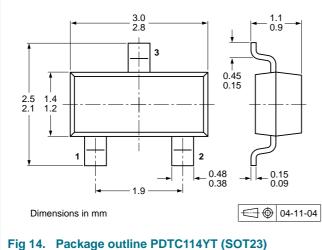
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline





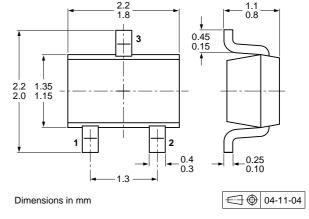


Fig 15. Package outline PDTC114YU (SOT323/SC-70)

NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 47 kΩ

10. Packing information

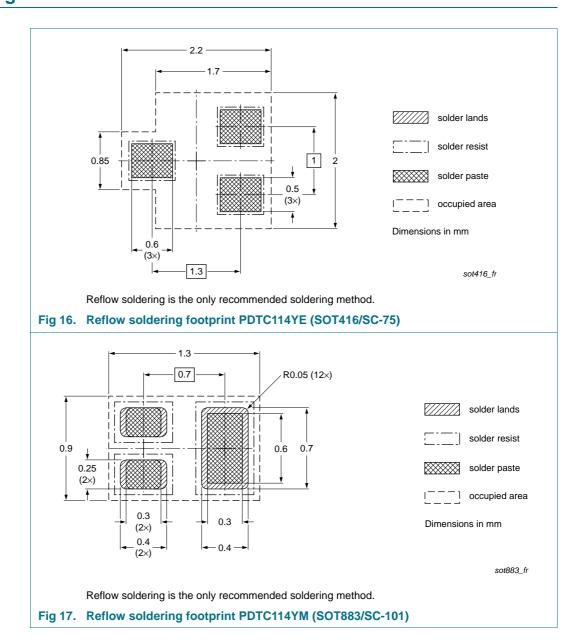
Table 9. Packing methods

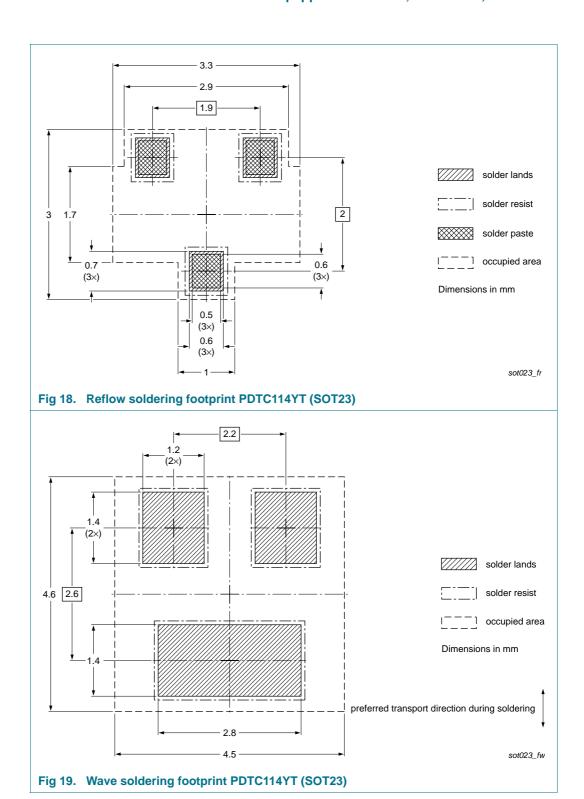
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

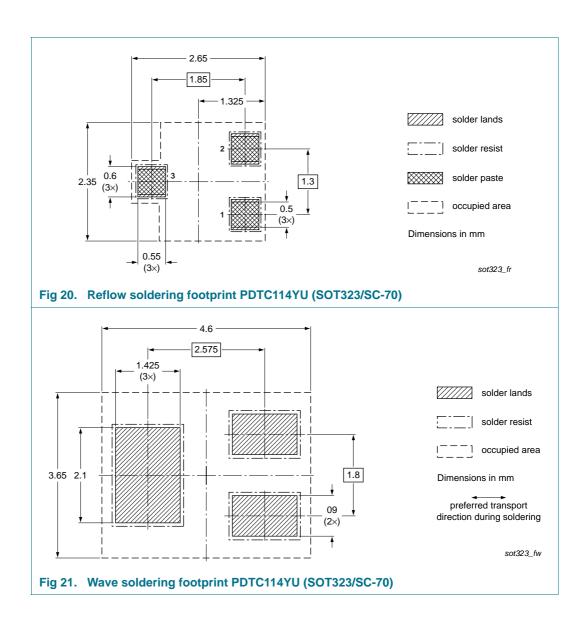
Type number	Package	Description	Packing	Packing quantity		
			3000	5000	10000	
PDTC114YE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTC114YM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTC114YT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTC114YU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

^[1] For further information and the availability of packing methods, see <u>Section 14</u>.

11. Soldering







NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 47 kΩ

12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PDTC114Y_SER v.7	20111118	Product data sheet	-	PDTC114Y_SERIES v.6			
Modifications:		of this document has been re NXP Semiconductors.	edesigned to comply wi	th the new identity			
	 Legal texts h 	ave been adapted to the ne	ew company name whe	re appropriate.			
	 Type numbe 	rs PDTC114YEF, PDTC114	YK and PDTC114YS re	emoved.			
	 Section 1 "P 	Section 1 "Product profile": updated					
	 Section 3 "O 	Section 3 "Ordering information": added					
	Section 4 "Marking": updated						
	 Figure 1 to 1 	1: added					
	 Section 5 "Limiting values": updated 						
	 Section 6 "TI 	hermal characteristics": upd	lated				
		uracteristics": V _{i(on)} redefined e input voltage, I _{CEO} update		voltage, $V_{i(off)}$ redefined to			
	 Section 8 "Te 	est information": added					
	 Section 9 "Page 12" 	ackage outline": supersede	d by minimized package	e outline drawings			
	 Section 10 "I 	Packing information": added	d				
	 Section 11 "S 	Soldering": added					
	 Section 13 "I 	<u>_egal information"</u> : updated					
PDTC114Y_SERIES v.6	20040817	Product data sheet	-	PDTC114Y_SERIES v.5			
PDTC114Y_SERIES v.5	20040910	Product specification	-	PDTC114Y_SERIES v.4			
PDTC114Y_SERIES v.4	20030414	Product specification	-	-			

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTC114Y series

NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 47 k Ω

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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PDTC114Y series

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15. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values 3
6	Thermal characteristics 4
7	Characteristics 7
8	Test information 9
8.1	Quality information
9	Package outline
10	Packing information 10
11	Soldering 11
12	Revision history
13	Legal information
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks 16
14	Contact information
15	Contents

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